

Magnetic Dynamical Properties and Ferromagnetic Resonance in (Ga,Mn)N Layers

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Here we investigate both experimentally and theoretically the magnetic properties of GaN doped with Mn. The MBE grown ferromagnetic $Ga_{1-x}Mn_xN$ layers, with x = 6%, are studied by a superconducting quantum interference device (SQUID) and ferromagnetic resonance (FMR). The experimental data is analysed using a newly developed atomistic spin model on few thousand Mn ion coupled by superexchange. The magnetic moment M and the microwave power absorbed during a ferromagnetic resonance[1] is calcu-

Experimental Results





Resonance field with angle to the (Ga,Mn)N c-axis

lated after the system has reached a steady state. Preliminary numerical results on small systems verifies the correctness of the applied model. This is the first ever simulation effort aimed at calculation of both magnetization and FMR in dilute magnetic semiconductor using atomistic approach.

Numerical Model

The magnetic moment of i^{th} Mn³⁺ ion is S_i . The classical Heisenberg Hamiltonian^[2] is Trigonal





The stochastic Landau-Lifshitz-Gilbert (sLLG) equation





Magnetization along easy axis

Magnetization along hard axis

Mono Spin Model Results









Analytical Model

Atomistic Simulation Results



Conclusion

We observe both uniaxial (trigonal) & cubic (Jahn-Teller) anisotropy in FMR curves.

$\partial \Phi$ $\partial \Theta$

Conditions



A noise free FMR simulation data at higher T not only demands more computational time but also requires a larger simulation box. To this end, to produce a proper simulated FMR curve that agrees with our experimental data at T=5.5 K, requires huge simulation box and higher computational time.

Reference & Acknowledgment

- 1. K. D. Usadel, Phys. Rev. B 73, 212405 (2006).
- 2. Y. K. Edathumkandy and D. Sztenkiel, arXiv :2108.01474
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